

# STPS30H100DJF

### Power Schottky rectifier

#### Datasheet – production data

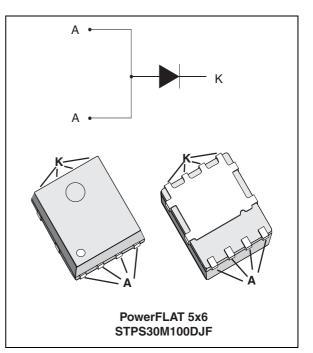
### Features

- Very low conduction losses
- Low forward voltage drop
- Low thermal resistance
- High specified avalanche capability
- High integration
- ECOPACK<sup>®</sup>2 compliant component

### Description

The STPS30H100DJF is a power Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Housed in a PowerFLAT<sup>™</sup> package, this device is intended to be used in adaptors requiring good efficiency at both low and high load. Its low profile was especially designed to be used in applications with space-saving constraints.



#### Table 1.Device summary

Symbol	Value
I <sub>F(AV)</sub>	30 A
V <sub>RRM</sub>	100 V
Тj	150 °C
V <sub>F</sub> (typ)	0.56 V

TM: PowerFLAT is a trademark of STMicroelectronics

Doc ID 023024 Rev 1

This is information on a product in full production.

#### **Characteristics** 1

Table 2.	Absolute ratings (limiting values, anode terminals short circuited)
	Absolute lutilitys (initiality values, anote terminals short broated)

Parameter	Value	Unit	
Repetitive peak reverse voltage		100	V
Forward rms current		45	А
Average forward current $\delta = 0.5$ $T_c = 100 \ ^{\circ}C$		30	А
Surge non repetitive forward current	turge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		А
Repetitive peak avalanche power $t_p = 1 \ \mu s, T_j = 25 \ ^{\circ}C$		3700	W
		120	V
Storage temperature range	-65 to +175	°C	
Maximum operating junction temperatu	150	°C	
	Repetitive peak reverse voltage Forward rms current Average forward current $\delta = 0.5$ Surge non repetitive forward current Repetitive peak avalanche power Maximum repetitive peak avalanche voltage Storage temperature range	Repetitive peak reverse voltageForward rms currentAverage forward current $T_c = 100 \degree C$ Surge non repetitive forward current $t_p = 10 \mbox{ ms sinusoidal}$ Repetitive peak avalanche power $t_p = 1 \mbox{ µs, } T_j = 25 \degree C$ Maximum repetitive peak avalanche $t_p < 1 \mbox{ µs, } T_j < 150 \degree C$ Voltage $I_{AR} < 9.3A$	Repetitive peak reverse voltage100Forward rms current100Forward rms current45Average forward current $\delta = 0.5$ $T_c = 100 \ ^{\circ}C$ 30Surge non repetitive forward current $t_p = 10 \ ^{\circ}ms \ ^{\circ}sinusoidal$ 250Repetitive peak avalanche power $t_p = 1 \ ^{\mu}s, \ T_j = 25 \ ^{\circ}C$ 3700Maximum repetitive peak avalanche $t_p < 1 \ ^{\mu}s, \ T_j < 150 \ ^{\circ}C$ 120Storage temperature range-65 to +175

1.  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

#### Table 3. Thermal resistance

Symbol	Parameter	Value	Unit	
R <sub>th(j-c)</sub>	Junction to case	2	°C/W	

#### Table 4. Static electrical characteristics (anode terminals short circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
IR <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 25 °C	V _V	-	-	6	μΑ	
	T <sub>j</sub> = 125 °C	V <sub>R</sub> =V <sub>RRM</sub>	-	2.5	6.5	mA	
V <sub>F</sub> <sup>(1)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	l <sub>F</sub> = 15 A	-	-	0.76	v	
	T <sub>j</sub> = 125 °C		-	0.56	0.62		
	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 30 A	-	-	0.84	v	
		T <sub>j</sub> = 125 °C	1 <sub>F</sub> – 30 A	-	0.63	0.71	

1. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses use the following equation: P = 0.60 x  $I_{F(AV)}$  + 0.00367 x  ${I_F}^2_{(RMS)}$ 



1.0 0.9

0.8 0.7

0.6 0.5

0.4

0.3 0.2

0.1

0.0

1.E-05

1.E-04

T<sub>amb</sub>(°C)

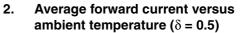
125

150

100

100

# Figure 1. Average forward power dissipation Figure 2. versus average forward current



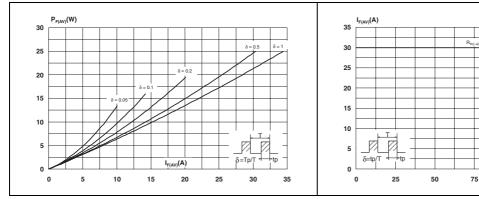
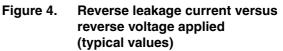


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration



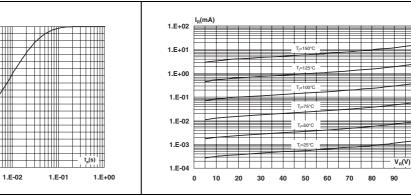
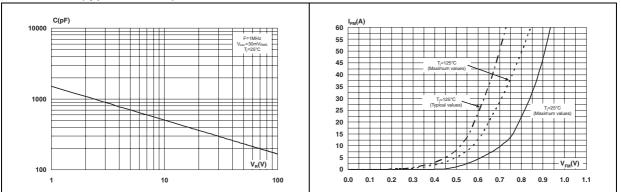


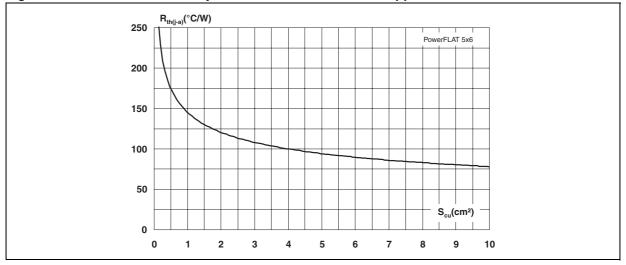
Figure 5. Junction capacitance versus reverse voltage applied (typical values)

1.E-03

Figure 6. Forward voltage drop versus forward current







#### Figure 7. Thermal resistance junction to ambient versus copper surface under tab



57

### 2 Package information

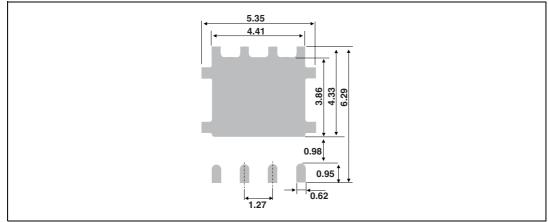
- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5.PowerFLAT 5x6 dimensions

		Dimensions					
	Ref.	М	lillimete	rs		Inches	
		Min.	Тур.	Max.	Min.	Тур.	Max.
	А	0.80		1.00	0.031		0.039
Γ	A1	0.02		0.05	0.001		0.002
	A2		0.25			0.010	
	b	0.30		0.50	0.012		0.020
$\begin{array}{c c} A_{\downarrow} & \downarrow \\ A_{1} & \Box & \downarrow \\ A_{1} & \Box & \downarrow \\ A_{2} & A_{2} & A_{2} \end{array}$	D		5.20			0.205	
	D2	4.11		4.31	0.162		0.170
	е		1.27			0.050	
E	E		6.15			0.242	
	E2	3.50		3.70	0.138		0.146
	L	0.50		0.80	0.020		0.031
	К	1.275		1.575	0.050		0.062

#### Figure 8. Footprint (dimensions in mm)



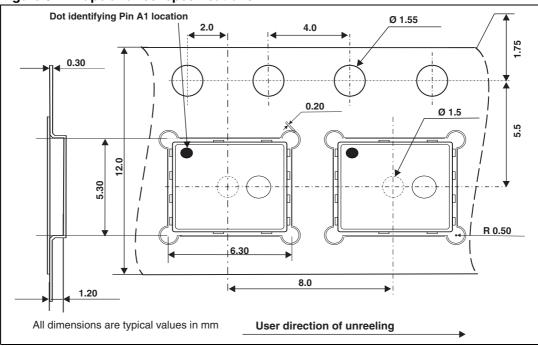


Figure 9. Tape and reel specifications



## **3** Ordering information

#### Table 6.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode	
STPS30H100DJF-TR	PS30 H100	PowerFLAT 5x6	95 mg	3000	Tape and reel	

## 4 Revision history

#### Table 7.Document revision history

Date	Revision	Changes
29-Mar-2012	1	Initial release.



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